

# Bi-directional 3.3V Normal Capacitance ESD Protector

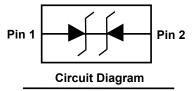
### **Description**

The PESDNC2XD3V3B protects sensitive semiconductor components from damage or upset due to electrostatic discharge (ESD) and other voltage induced transient events. They feature large cross-sectional area junctions for conducting high transient currents, offer desirable electrical characteristics for board level protection, such as fast response time, low operating voltage. It gives designer the flexibility to protect one unidirectional line in applications where arrays are not practical.



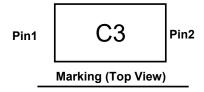
### **Feature**

- DFN0603-2L package
- Replacement for MLV(0201)
- Bidirectional configurations
- Response time is typically < 1 ns</p>
- Low clamping voltage
- RoHS compliant
- Transient protection for data lines to IEC 61000-4-2(ESD)
   ±30KV(air), ±25KV(contact).



### **Applications**

- Cellular phones
- Portable devices
- Digital cameras
- Power supplies

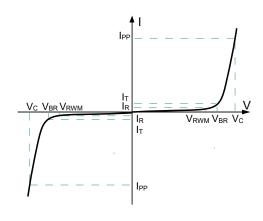


### **Mechanical Characteristics**

- Mounting position: Any
- Qualified max reflow temperature:260°C
- Device meets MSL 1 requirements
- DFN0603-2L without plating

### **Electronics Parameter**

Symbol	Parameter		
V <sub>RWM</sub>	Peak Reverse Working Voltage		
I <sub>R</sub>	Reverse Leakage Current @ V <sub>RWM</sub>		
V <sub>BR</sub>	Breakdown Voltage @ I⊤		
lτ	Test Current		
I <sub>PP</sub>	Maximum Reverse Peak Pulse Current		
Vc	Clamping Voltage @ IPP		
P <sub>PP</sub>	Peak Pulse Power		
CJ	Junction Capacitance		
lF	Forward Current		
V <sub>F</sub>	Forward Voltage @ I <sub>F</sub>		



# Electrical characteristics per line@25℃( unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Peak Reverse Working Voltage	V <sub>RWM</sub>				3.3	V
Breakdown Voltage	V <sub>BR</sub>	I <sub>t</sub> = 1mA	4.0		6.5	V
Reverse Leakage Current	I <sub>R</sub>	V <sub>RWM</sub> =3.3V T=25°C			1.0	μA
Clamping Voltage	V <sub>CL</sub>	I <sub>PP</sub> =16A t <sub>p</sub> =100ns		10.0		V
Clamping Voltage	Vc	I <sub>PP</sub> = 1A t <sub>P</sub> = 8/20µs		6.5	8.0	V
Clamping Voltage	Vc	I <sub>PP</sub> = 6A t <sub>P</sub> = 8/20µs		8.0	10.0	V
Junction Capacitance	C <sub>j</sub>	V <sub>R</sub> =0V f = 1MHz		12.0	20.0	pF

# Absolute maximum rating@25℃

Rating	Symbol	Value	Units
Peak Pulse Power (t <sub>p</sub> =8/20µS)	P <sub>pp</sub>	60	W
Operating Temperature	TJ	-55 to 150	°C
Storage Temperature	T <sub>STG</sub>	-55 to 150	℃

# Typical Characteristics

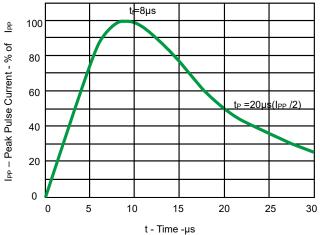


Fig 1.Pulse Waveform

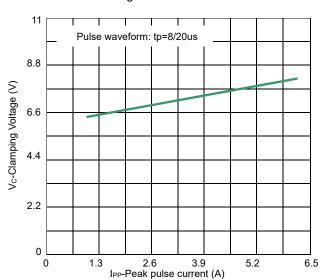


Fig 3. Clamping voltage vs. Peak pulse current

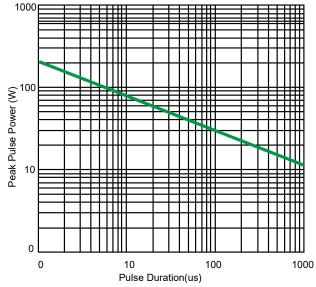


Fig 5. Non Repetitive Peak Pulse Power vs. Pulse time

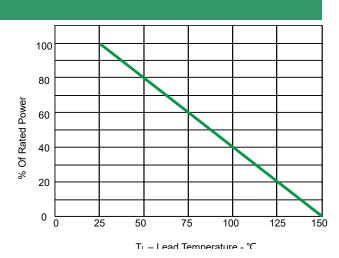


Fig 2.Power Derating Curve

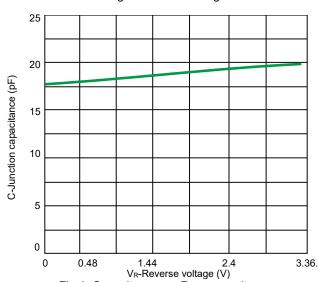


Fig 4. Capacitance vs. Reveres voltage

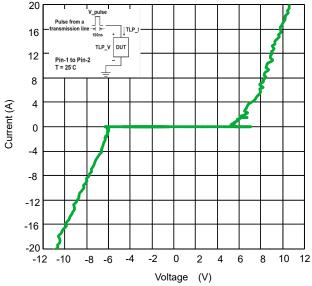
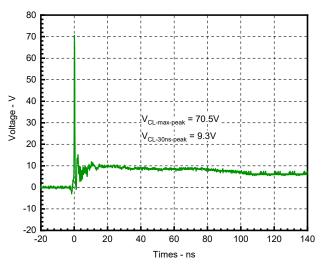


Fig 6. TLP Measurement



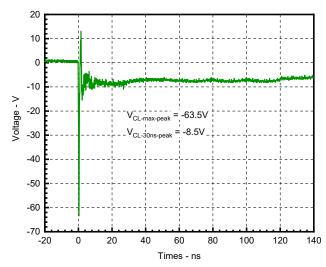
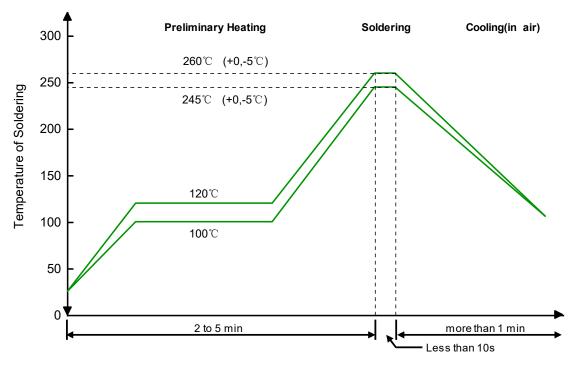


Fig 7. Clamping Voltage at IEC61000-4-2 +8kV Pulse Waveform

Fig 8. Clamping Voltage at IEC61000-4-2
-8kV Pulse Waveform

### **Solder Reflow Recommendation**



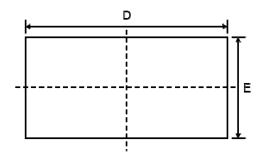
Remark: Pb free for 260°C; Pb for 245°C.

### **PCB** Design

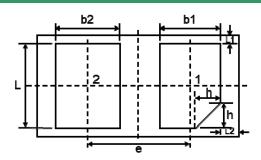
For TVS diodes a low-ohmic and low-inductive path to chassis earth is absolutely mandatory in order to achieve good ESD protection. Novices in the area of ESD protection should take following suggestions to heart:

- Do not use stubs, but place the cathode of the TVS diode directly on the signal trace.
- Do not make false economies and save copper for the ground connection.
- Place via holes to ground as close as possible to the anode of the TVS diode.
- Use as many via holes as possible for the ground connection.
- Keep the length of via holes in mind! The longer the more inductance they will have.

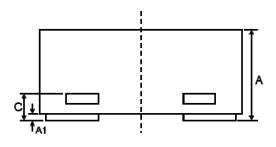
# Product dimension (DFN0603-2L)



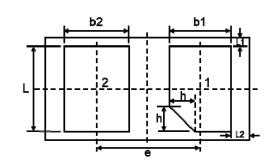
Top View



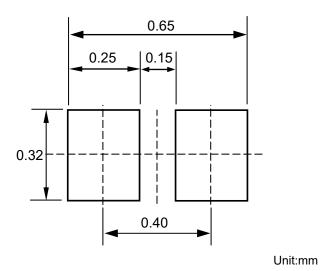
**Bottom View** 



Side View



Bottom View (Optional)



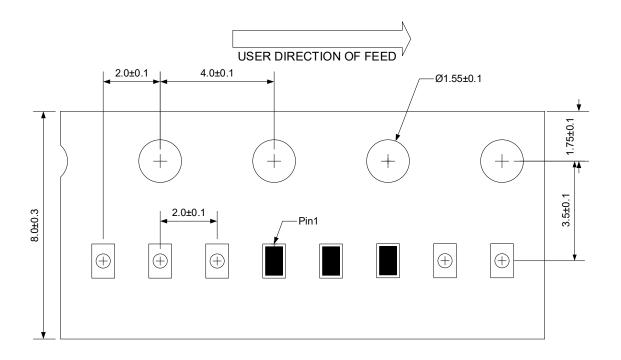
Suggested PCB Layout

Dim	Millim	neters	Inches		
Dilli	Min	Max	Min	Max	
Α	0.27	0.35	0.011	0.014	
A1	0.00	0.05	0.000	0.002	
b1	0.13	0.23	0.005	0.009	
b2	0.14	0.24	0.006	0.009	
С	0.05	0.15	0.002	0.006	
D	0.55	0.65	0.022	0.026	
е	0.35 BSC		0.014 BSC		
L1	0.025 BSC		0.001 BSC		
L2	0.035 BSC		0.001 BSC		
Е	0.25	0.35	0.010	0.014	
L	0.20	0.30	0.008	0.012	
h	0.00	0.10	0.000	0.004	

## **Ordering information**

Device	Package	Reel	Shipping
PESDNC2XD3V3B	DFN0603-2L (Pb-Free)	7"	10000 / Tape & Reel

## Load with information



Unit:mm

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